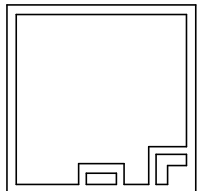
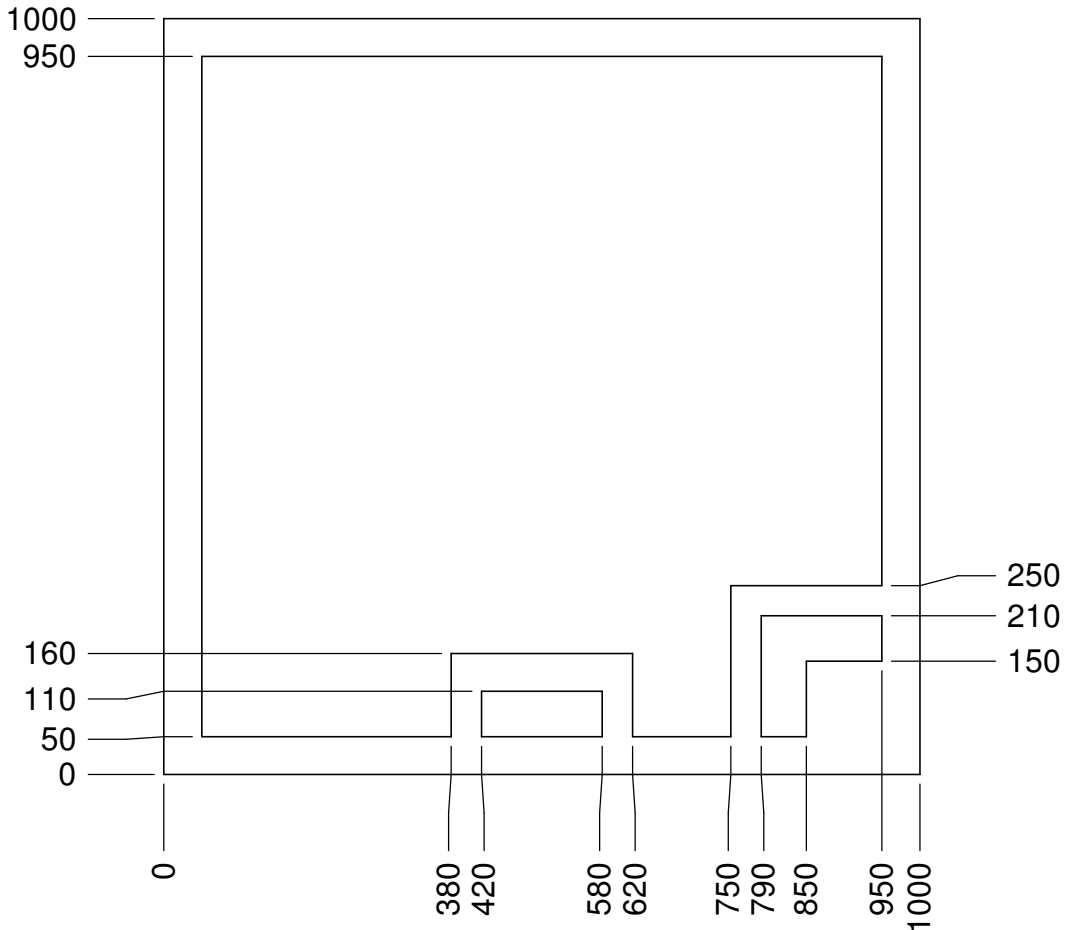


REVISIONS				
DATE	REV.	ECO	DESCRIPTION	APPROVED



SCALE 25:1

Notes: (Unless Otherwise Specified).

- 1) DIE MATERIAL IS SILICON.
- 2) DIE THICKNESS IS 250 μm (10 MIL).
- 3) METALLIZATION 1.0 μm ALUMINUM (Al) OVER 0.75 μm SiO_2 .
- 4) DIE IS WITHOUT PASSIVATION.
- 5) WIRE BONDABLE WITH GOLD (Au) OR ALUMINUM (Al) WIRE.
- 6) DIFFERENTIAL PAIR (2 PADS) WITH LARGE GROUND PAD.
- 7) RF / MICROWAVE PARASITIC TEST APPLICATIONS.
- 8) TOLERANCE = $\pm 1 \mu\text{m}$.

DIMENSIONS IN MICRONS
1000 μm = 1.0mm

PART NUMBER SYSTEM						
TD	-	2	-	1.0	-	DIF
SILICON TEST DIE	BOND PADS	DIE SIZE (mm)	DIFFERENTIAL PAIR			

TOLERANCE UNLESS NOTED	
X.XX	+/- 0.01
X.XXX	+/- 0.005
X.XXXX	+/- 0.0005
ANGLES	+/- 0.5°
ALL DIMENSIONS IN	
<input checked="" type="checkbox"/> INCHES	<input type="checkbox"/> MILLIMETERS
THIRD ANGLE PROJECTION	

APPROVALS	DATE
DRAWN J. HINES	4/2/2010
ENG	
MFG	
QA	
CUST	
REVISED	

TITLE Si TEST DIE TD SERIES			
SCALE 100:1	SIZE A	DRAWING NO. 151002	REV A
DO NOT SCALE DRAWING		SHEET 1 OF 1	